

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









2225-4L

3.5 Watts, 24 Volts, Class C Microwave 2200-2500 MHz

GENERAL DESCRIPTION

The 2225-4L is a COMMON BASE transistor capable of providing 3.5 Watts, Class C output power over the band 2200-2500 MHz. The transistor includes input prematching for full broadband capability. Gold metalization and diffused ballasting are used to provide high reliability and supreme ruggedness. The transistor uses a fully hermetic High Temperature Solder Sealed package.

ABSOLUTE MAXIMUM RATINGS

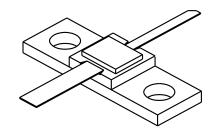
Maximum Power Dissipation @ 25°C 10 Watts

Maximum Voltage and Current

BVces Collector to Emitter Voltage 40 Volts
BVebo Emitter to Base Voltage 3.5 Volts
Ic Collector Current 0.6 Amps

Maximum Temperatures

Storage Temperature $-65 \text{ to} + 200 ^{\circ}\text{C}$ Operating Junction Temperature $+200 ^{\circ}\text{C}$ CASE OUTLINE 55LV, STYLE 1



ELECTRICAL CHARACTERISTICS @ 25 °C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Pout Pin Pg	Power Out Power Input Power Gain	F = 2200-2500 MHz Vcc = 24 Volts	3.5 8.5		0.5	Watts Watts dB
ηc VSWR	Efficiency Load Mismatch Tolerance	Pout =3.5Watts		40	10:1	%

BVces BVebo	Collector to Emitter Breakdown Emitter to Base Breakdown	Ic = 10 mA $Ie = 5 mA$	40 3.5			Volts Volts
Hfe	Current Gain	Vce = 5V, Ic = 200 mA	20		120	
Cob	Output Capacitance	Vcb = 24 F = 1 MHz		7		pF
θјс	Thermal Resistance	$Tc = 25^{\circ}C$			17.0	°C/W

Initial Issue July, 1994

GHz TECHNOLOGY INC. RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE. GHZ RECOMMENDS THAT BEFORE THE PRODUCT(S) DESCRIBED HEREIN ARE WRITTEN INTO SPECIFICATIONS, OR USED IN CRITICAL APPLICATIONS, THAT THE PERFORMANCE CHARACTERISTICS BE VERIFIED BY CONTACTING THE FACTORY.